

# IR-Lumineszenzdiode (850 nm) mit hoher Ausgangsleistung

High Power Infrared Emitter (850 nm)

Lead (Pb) Free Product - RoHS Compliant

SFH 4250



## Vorläufige Daten / Preliminary Data

### Wesentliche Merkmale

- Infrarot LED mit sehr hoher Ausgangsleistung
- Emissionswellenlänge typ. 850 nm
- Hohe Bestromung bei hohen Temperaturen möglich

### Anwendungen

- Infrarotbeleuchtung für CMOS Kameras
- IR-Datenübertragung
- Sensorik

### Sicherheitshinweise

Je nach Betriebsart emittieren diese Bauteile hochkonzentrierte, nicht sichtbare Infrarot-Strahlung, die gefährlich für das menschliche Auge sein kann. Produkte, die diese Bauteile enthalten, müssen gemäß den Sicherheitsrichtlinien der IEC-Normen 60825-1 und 62471 behandelt werden.

### Features

- High Power Infrared LED
- Peak wavelength typ. 850 nm
- High forward current allowed at high temperature

### Applications

- Infrared Illumination for CMOS cameras
- IR Data Transmission
- Optical sensors

### Safety Advices

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

Typ Type	Bestellnummer Ordering Code	Strahlstärkegruppierung <sup>1)</sup> ( $I_F = 100 \text{ mA}$ , $t_p = 20 \text{ ms}$ ) Radiant Intensity Grouping <sup>1)</sup> $I_e (\text{mW/sr})$
SFH 4250	Q65110A2465	$\geq 10$ (typ. 15)

<sup>1)</sup> gemessen bei einem Raumwinkel  $\Omega = 0.01 \text{ sr}$  / measured at a solid angle of  $\Omega = 0.01 \text{ sr}$



ATTENTION - Observe Precautions For Handling - Electrostatic Sensitive Device

**Grenzwerte ( $T_A = 25^\circ\text{C}$ )****Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{\text{op}}, T_{\text{stg}}$	- 40 ... + 100	°C
Sperrspannung Reverse voltage	$V_R$	5	V
Vorwärtsgleichstrom Forward current	$I_F$	100	mA
Stoßstrom, $t_p = 100 \mu\text{s}, D = 0$ Surge current	$I_{\text{FSM}}$	1.5	A
Verlustleistung Power dissipation	$P_{\text{tot}}$	180	mW
Wärmewiderstand Sperrsicht - Umgebung bei Montage auf FR4 Platine, Padgröße je 16 mm <sup>2</sup> Thermal resistance junction - ambient mounted on PC-board (FR4), padsize 16 mm <sup>2</sup> each	$R_{\text{thJA}}$	300	K/W
Wärmewiderstand Sperrsicht - Lötstelle bei Montage auf Metall-Block Thermal resistance junction - soldering point, mounted on metal block	$R_{\text{thJS}}$	140	K/W

**Kennwerte ( $T_A = 25^\circ\text{C}$ )****Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der Strahlung Wavelength at peak emission $I_F = 100 \text{ mA}$	$\lambda_{\text{peak}}$	850	nm
Spektrale Bandbreite bei 50% von $I_{\text{max}}$ Spectral bandwidth at 50% of $I_{\text{max}}$ $I_F = 100 \text{ mA}$	$\Delta\lambda$	35	nm
Abstrahlwinkel Half angle	$\varphi$	$\pm 60$	Grad deg.
Aktive Chipfläche Active chip area	$A$	0.09	mm <sup>2</sup>
Abmessungen der aktiven Chipfläche Dimension of the active chip area	$L \times B$ $L \times W$	$0.3 \times 0.3$	mm <sup>2</sup>

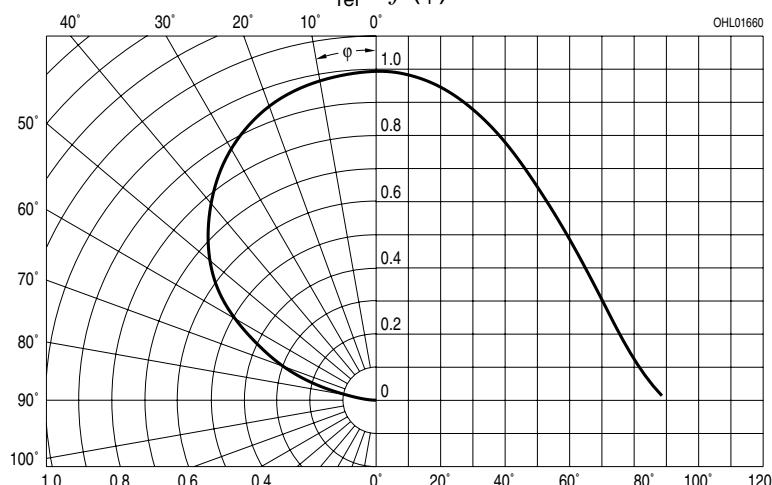
**Kennwerte ( $T_A = 25^\circ\text{C}$ )****Characteristics (cont'd)**

<b>Bezeichnung Parameter</b>	<b>Symbol Symbol</b>	<b>Wert Value</b>	<b>Einheit Unit</b>
Schaltzeiten, $I_e$ von 10% auf 90% und von 90% auf 10%, bei $I_F = 100 \text{ mA}$ , $R_L = 50 \Omega$ Switching times, $I_e$ from 10% to 90% and from 90% to 10%, $I_F = 100 \text{ mA}$ , $R_L = 50 \Omega$	$t_r, t_f$	12	ns
Durchlassspannung Forward voltage $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$ $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	$V_F$ $V_F$	1.5 (< 1.8) 2.4 (< 3.0)	V V
Sperrstrom Reverse current $V_R = 5 \text{ V}$	$I_R$	not designed for reverse operation	$\mu\text{A}$
Gesamtstrahlungsfluss Total radiant flux $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$\Phi_e \text{ typ}$	40	mW
Temperaturkoeffizient von $I_e$ bzw. $\Phi_e$ , $I_F = 100 \text{ mA}$ Temperature coefficient of $I_e$ or $\Phi_e$ , $I_F = 100 \text{ mA}$	$TC_I$	- 0.5	%/K
Temperaturkoeffizient von $V_F$ , $I_F = 100 \text{ mA}$ Temperature coefficient of $V_F$ , $I_F = 100 \text{ mA}$	$TC_V$	- 0.7	mV/K
Temperaturkoeffizient von $\lambda$ , $I_F = 100 \text{ mA}$ Temperature coefficient of $\lambda$ , $I_F = 100 \text{ mA}$	$TC_\lambda$	+ 0.2	nm/K

**Strahlstärke  $I_e$  in Achsrichtung<sup>1)</sup>**gemessen bei einem Raumwinkel  $\Omega = 0.01 \text{ sr}$ **Radiant Intensity  $I_e$  in Axial Direction**at a solid angle of  $\Omega = 0.01 \text{ sr}$ 

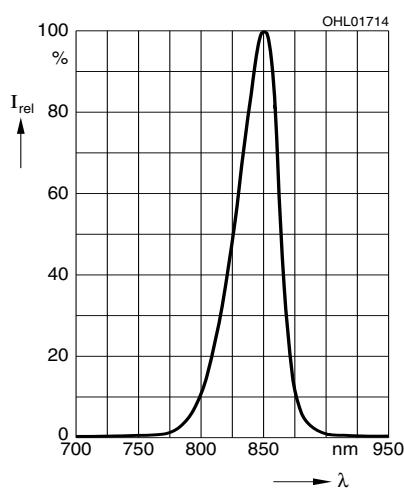
Bezeichnung Parameter	Symbol	Werte Values		Einheit Unit
		SFH 4250-R	SFH 4250-S	
Strahlstärke Radiant intensity $I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$I_{e \min}$ $I_{e \max}$	10 20	16 32	mW/sr mW/sr
Strahlstärke Radiant intensity $I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	$I_{e \text{ typ}}$	100	140	mW/sr

<sup>1)</sup> Nur eine Gruppe in einer Verpackungseinheit (Streuung kleiner 2:1) /  
Only one group in one packing unit (variation lower 2:1)

**Abstrahlcharakteristik****Radiation Characteristics  $I_{\text{rel}} = f(\phi)$** 

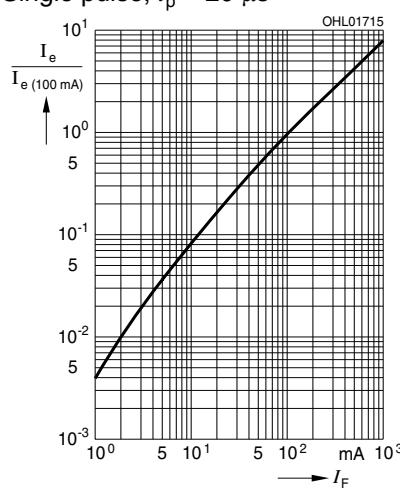
**Relative Spectral Emission**

$$I_{\text{rel}} = f(\lambda)$$

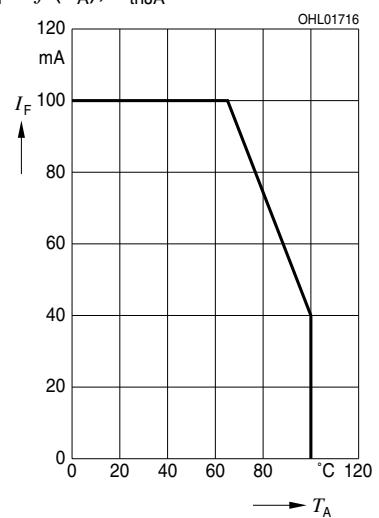


**Radiant Intensity**  $\frac{I_e}{I_e \text{ 100 mA}} = f(I_F)$

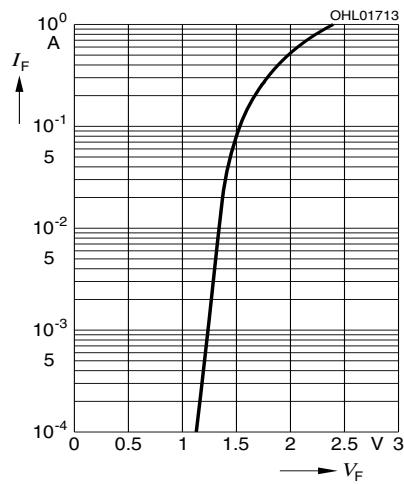
Single pulse,  $t_p = 20 \mu\text{s}$

**Max. Permissible Forward Current**

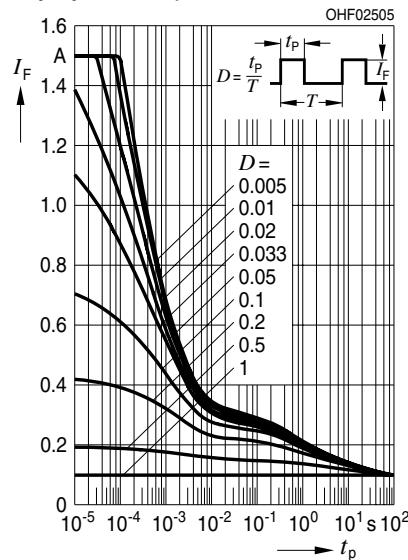
$$I_F = f(T_A), R_{\text{thJA}} = 300 \text{ K/W}$$

**Forward Current  $I_F = f(V_F)$** 

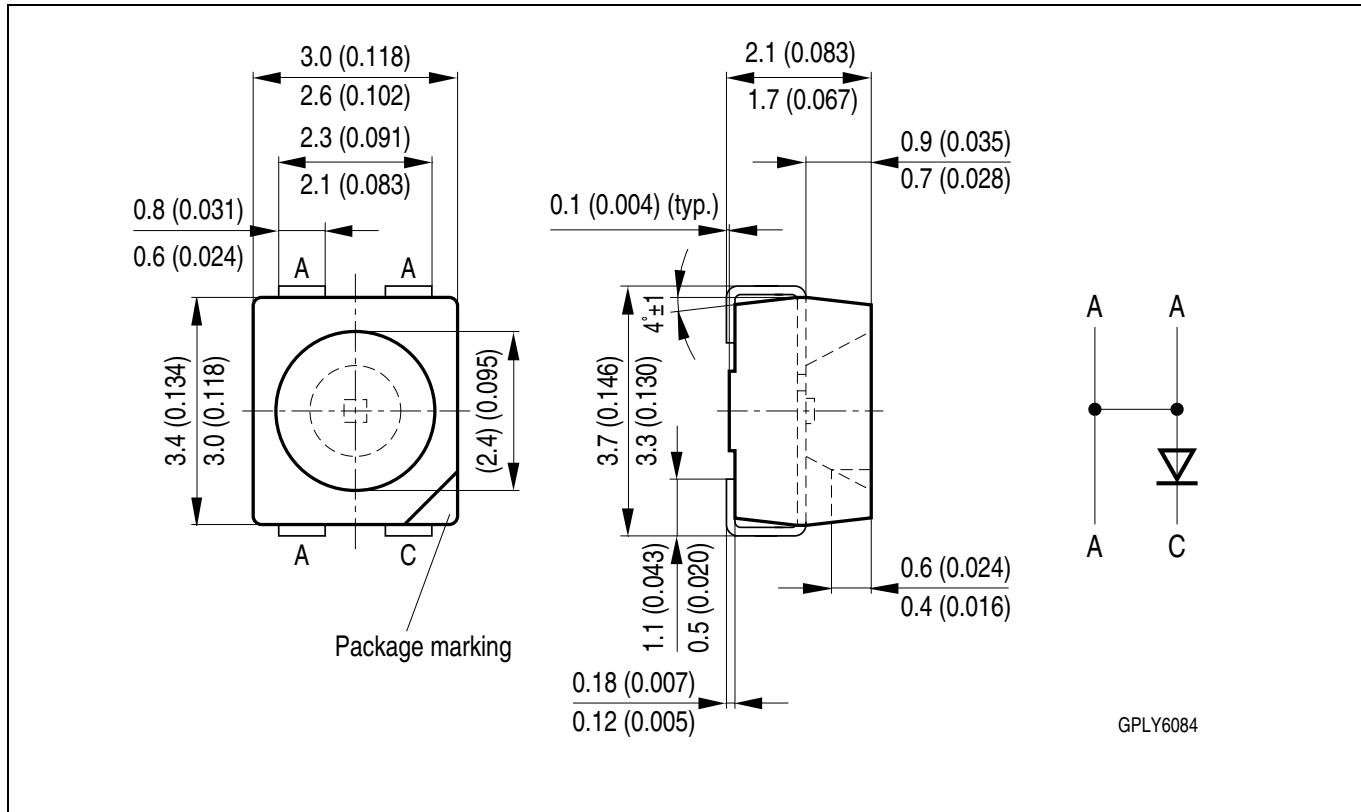
Single pulse,  $t_p = 20 \mu\text{s}$

**Permissible Pulse Handling**

**Capability**  $I_F = f(\tau), T_A \leq 65 \text{ }^\circ\text{C}$ ,  
duty cycle  $D = \text{parameter}$



**Maßzeichnung**  
**Package Outlines**

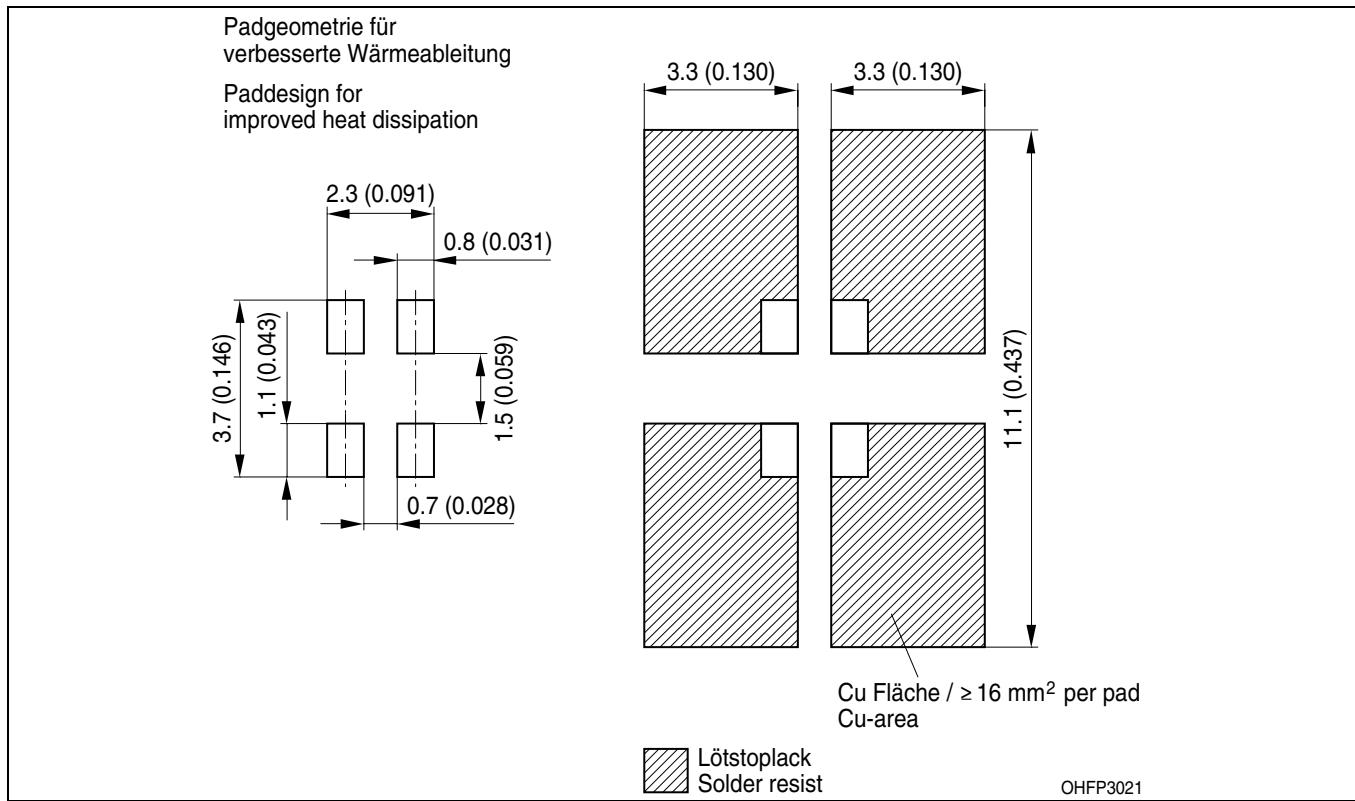


Maße in mm (inch) / Dimensions in mm (inch).

Gehäuse / Package	weiß, klarer Verguss / white, clear resin
Anschlussbelegung Pin configuration	Kathode: abgeschrägte Ecke Cathode: beveled edge

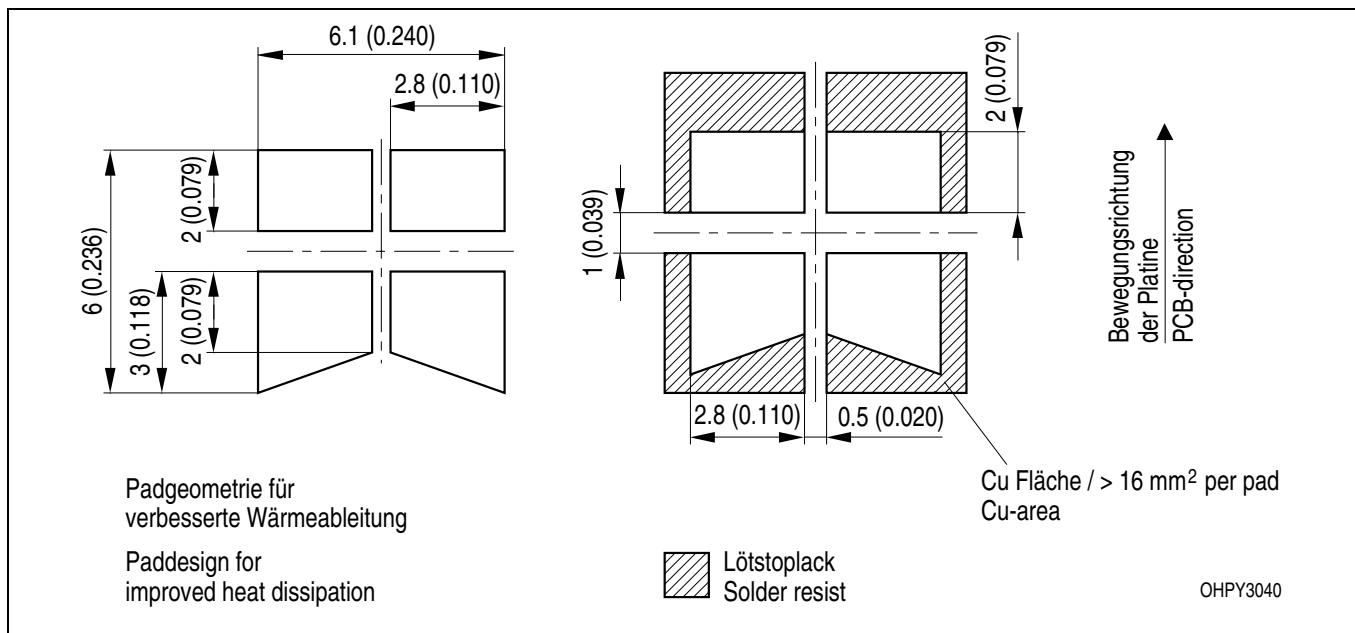
**Empfohlenes Lötpaddesign**  
Recommended Solder Pad Design

Reflow Löten  
Reflow Soldering



**Empfohlenes Lötpaddesign**  
Recommended Solder Pad Design

Wellenlöten TTW  
TTW Soldering



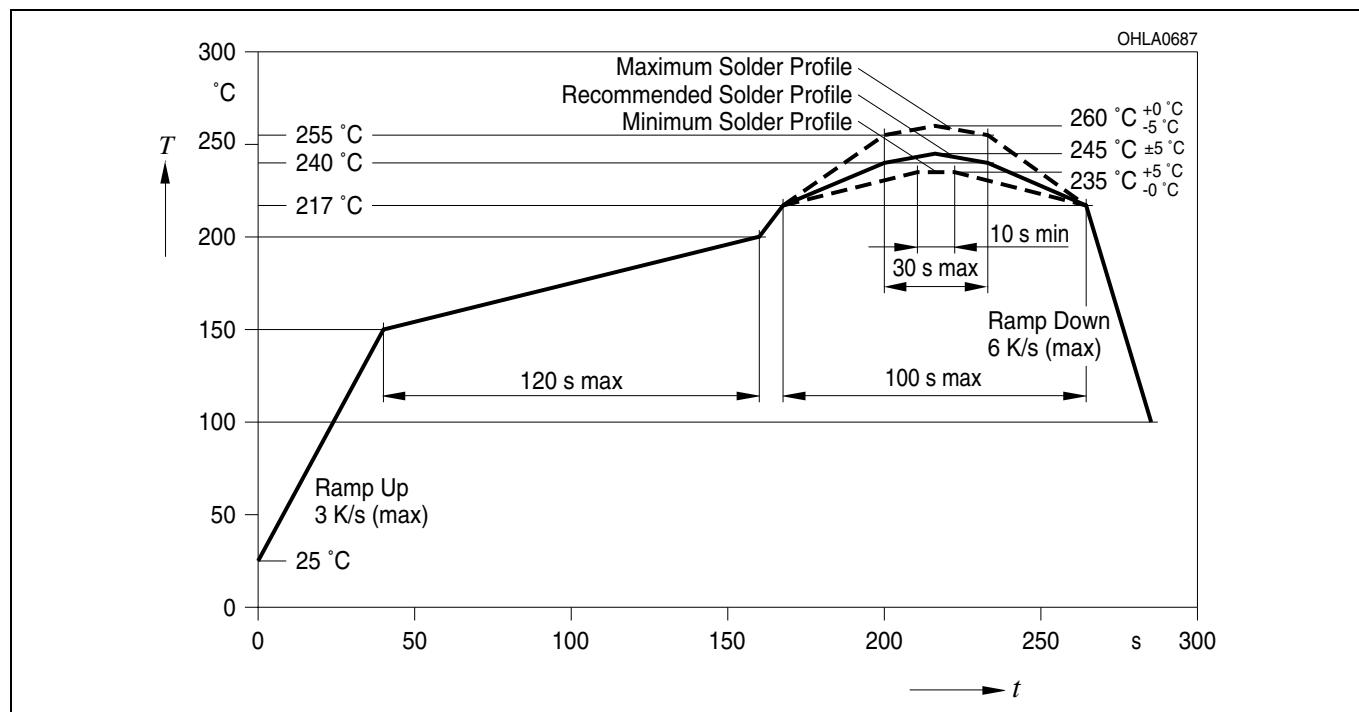
**Lötbedingungen****Soldering Conditions****Reflow Lötprofil für bleifreies Löten****Reflow Soldering Profile for lead free soldering**

Vorbehandlung nach JEDEC Level 2

Preconditioning acc. to JEDEC Level 2

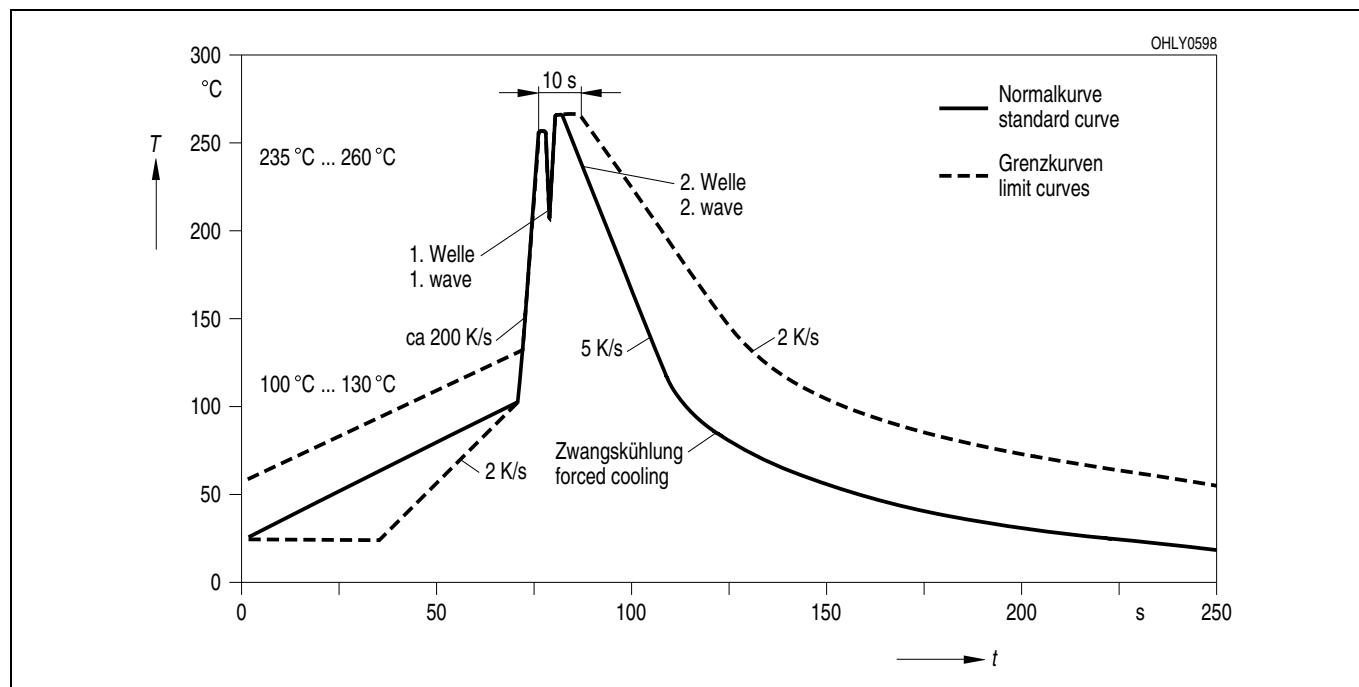
(nach J-STD-020C)

(acc. to J-STD-020C)

**Wellenlöten (TTW)****TTW Soldering**

(nach CECC 00802)

(acc. to CECC 00802)



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